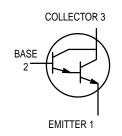
One Watt Darlington Transistors

NPN Silicon



MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	VCES	30	Vdc	
Collector-Base Voltage	VCBO	30	Vdc	
Emitter-Base Voltage	VEBO	10	Vdc	
Collector Current — Continuous	IC	1.0	Adc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	1.0 8.0	Watts mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	2.5 20	Watts mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta}JA$	125	°C/W
Thermal Resistance, Junction to Case	$R_{ extsf{ heta}JC}$	50	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristic	Symbo	l Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (I _C = 100 μ Adc, V _{BE} = 0)	V(BR)CE	S 30	-	Vdc
Collector Cutoff Current ($V_{CB} = 30 \text{ Vdc}, I_E = 0$)	ІСВО	-	100	nAdc
Emitter Cutoff Current (V _{EB} = 10 Vdc, I _C = 0)	IEBO	-	100	nAdc



MOTOROLA

MPSW13

MPSW14

MPSW13 MPSW14

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
ON CHARACTERISTICS(1)					
DC Current Gain (I _C = 10 mAdc, V _{CE} = 5.0 Vdc)	MPSW13 MPSW14	hFE	5,000 10,000		_
$(I_{C} = 100 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc})$	MPSW13 MPSW14		10,000 20,000		
Collector–Emitter Saturation Voltage (I _C = 100 mAdc, I _B = 0.1 mAdc)		VCE(sat)	—	1.5	Vdc
Base–Emitter On Voltage (I _C = 100 mAdc, V _{CE} = 5.0 Vdc)		VBE(on)	—	2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain — Bandwidth Product ⁽²⁾		fт	125	_	MHz

Current–Gain — Bandwidth Product(2) f_T (IC = 10 mAdc, VCE = 5.0 Vdc, f = 100 MHz)f

1. Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

2. $f_T = |h_{fe}| \bullet f_{test}$.

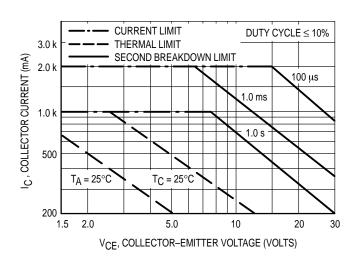


Figure 1. Active Region — Safe Operating Area

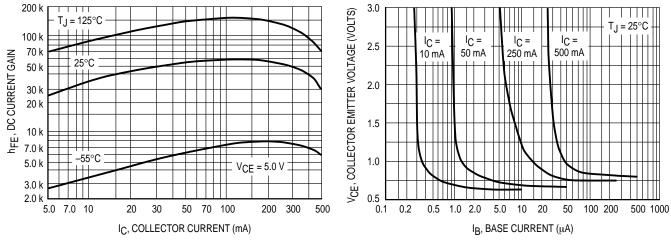
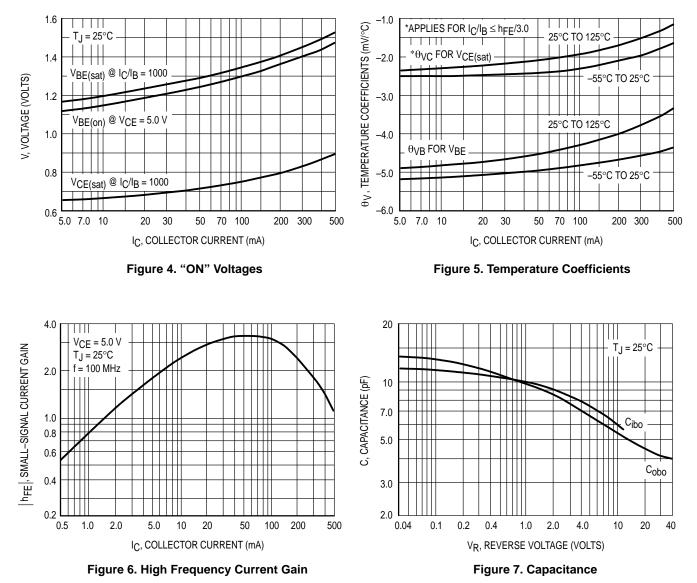


Figure 2. DC Current Gain

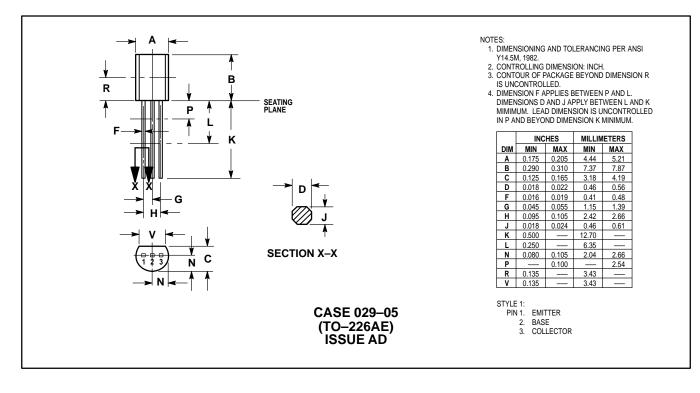
Figure 3. Collector Saturation Region

MPSW13 MPSW14



Motorola Small-Signal Transistors, FETs and Diodes Device Data

PACKAGE DIMENSIONS



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How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447 or 602–303–5454

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MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE 602-244-6609 INTERNET: http://Design-NET.com JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 03–81–3521–8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

